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FAIRCHILD

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74LCXH16245 Low Voltage 16-Bit Bidirectional Transceiver with Bushold

General Description

The LCXH16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The T/\overline{R} inputs determine the direction of data flow through the device. The \overline{OE} inputs disable both the A and B Ports by placing them in a high impedance state.

The LCXH16245 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The LCXH16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

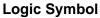
- 2.3V–3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power-down high impedance outputs
- Bushold on inputs eliminates the need for external pull-up/pull-down resistors
- \pm 24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance conforms to the requirements of JESD78
- ESD performance: Human body model > 2000V
- Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

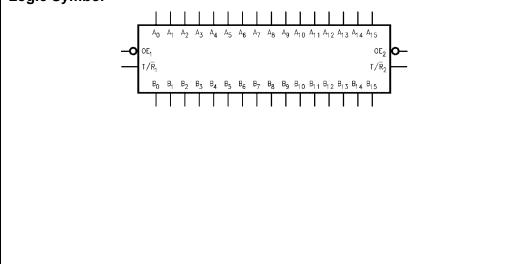
Ordering Code:

Order Number	Package Number	Package Description	
74LCXH16245G (Note 1) (Note 2)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide	
74LCXH16245MTD (Note 2)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide	

Note 1: Ordering Code "G" indicates Trays.

Note 2: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.





Connection Diagrams

Pin Assignr	nent for SSOP an	d TSSOP
τ∕π ₁ —	1 48	
в _о — в ₁ —	2 47 3 46	A_0
	4 45	— A ₁ — GND
	4 43 5 44	- A ₂
z	6 43	- A3
	7 42	- v _{cc}
CC CC	8 41	— A ₄
	9 40	— A ₅
	10 39	- GND
в ₆ —	11 38	— 4 ₆
+	12 37	— A ₇
	13 36	— A ₈
0	14 35	— A ₉
	15 34	- GND
в ₁₀ —	16 33	— A ₁₀
	17 32	- A ₁₁
	18 31	
	19 30	— A ₁₂
	20 29	— A ₁₃
	21 28	- GND
B ₁₄ —	22 27	— A ₁₄
B ₁₅ —	23 26	— A ₁₅
T∕R ₂ —	24 25	- OE ₂
Pin As	ssignment for FB	GA
-	123456	3
лна F Е D С В А	000000 000000 000000 000000 000000 00000	

Pin Descriptions

Pin Names	Description
OEn	Output Enable Input
T/R _n	Transmit/Receive Input
A ₀ -A ₁₅ B ₀ -B ₁₅	Side A Inputs or 3-STATE Outputs (Bushold)
B ₀ -B ₁₅	Side B Inputs or 3-STATE Outputs (Bushold)

FBGA Pin Assignments

	1	2	3	4	5	6
Α	B ₀	NC	T/R_1	OE ₁	NC	A ₀
В	B ₂	B ₁	NC	NC	A ₁	A ₂
С	B ₄	B ₃	V _{CC}	V _{CC}	A ₃	A ₄
D	B ₆	B ₅	GND	GND	A ₅	A ₆
E	B ₈	B ₇	GND	GND	A ₇	A ₈
F	B ₁₀	B ₉	GND	GND	A ₉	A ₁₀
G	B ₁₂	B ₁₁	V _{CC}	V _{CC}	A ₁₁	A ₁₂
н	B ₁₄	B ₁₃	NC	NC	A ₁₃	A ₁₄
J	B ₁₅	NC	T/\overline{R}_2	OE ₂	NC	A ₁₅

Truth Tables

Inp	outs	- Outputs			
OE ₁	T/R ₁	Bus B_0-B_7 Data to Bus A_0-A_7			
L	L	Bus $B_0 - B_7$ Data to Bus $A_0 - A_7$			
L	н	Bus $A_0 - A_7$ Data to Bus $B_0 - B_7$			
н	Х	HIGH Z State on A ₀ -A ₇ , B ₀ -B ₇			
Inp	uts	Outente			
OE ₂	T/R ₂	Outputs			
L	L	Bus B ₈ –B ₁₅ Data to Bus A ₈ –A ₁₅			
L	н	Bus A ₈ -A ₁₅ Data to Bus B ₈ -B ₁₅			
н	Х	HIGH Z State on A8-A15, B8-B15			
= High Impe		am			
	edance				

Symbol	Parameter	Value	Conditions	Units	
V _{CC}	Supply Voltage	-0.5 to +7.0		V	
VI	DC Input Voltage	–0.5 to V _{CC} + 0.5		V	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		–0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 4)		
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA	
I _{OK}	DC Output Diode Current	-50	V _O < GND		
		+50	$V_{O} > V_{CC}$	mA	
I _O	DC Output Source/Sink Current	±50		mA	
I _{CC}	DC Supply Current per Supply Pin	±100		mA	
I _{GND}	DC Ground Current per Ground Pin	±100		mA	
T _{STG}	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	V _{CC}	v
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V – 3.6V		±24	
		V _{CC} = 2.7V - 3.0V		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Floating or unused control inputs must be HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter		Conditions	v _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	
Symbol			Conditions	(V)	Min	Max	Units	
V _{IH}	HIGH Level Input Voltage			2.3 - 2.7	1.7		V	
				2.7 – 3.6	2.0		v	
VIL	LOW Level Input Voltage			2.3 – 2.7		0.7	V	
				2.7 - 3.6		0.8	V	
V _{OH}	HIGH Level Output Voltage		$I_{OH} = -100 \ \mu A$	2.3 - 3.6	V _{CC} - 0.2			
			I _{OH} = -8 mA	2.3	1.8			
			$I_{OH} = -12 \text{ mA}$	2.7	2.2		V	
			$I_{OH} = -18 \text{ mA}$	3.0	2.4			
			$I_{OH} = -24 \text{ mA}$	3.0	2.2			
V _{OL}	LOW Level Output Voltage		I _{OL} = 100 μA	2.3 - 3.6		0.2		
			I _{OL} = 8mA	2.3		0.6		
			I _{OL} = 12 mA	2.7		0.4	V	
			I _{OL} = 16 mA	3.0		0.4		
			I _{OL} = 24 mA	3.0		0.55		
I _I	Input Leakage Current	Data	$V_I = V_{CC}$ or GND	2.3 - 3.6		±5.0		
		Control	$O \leq V_1 \leq 5.5$	2.3 - 3.6		±5.0	μA	

DC Electrical Characteristics (Continued)

$T_A = -40^{\circ}C$ to $+85^{\circ}C$ V_{cc} Symbol Parameter Conditions Units Min Max (V) Bushold Input Minimum $V_{IN} = 0.7V$ 45 I_{I(HOLD)} 2.3 Drive Hold Current $V_{IN} = 1.7V$ -45 μA 75 $V_{IN}=0.8V\,$ 3.0 $V_{IN} = 2.0V$ -75 Bushold Input Over-Drive (Note 6) 300 I_{I(OD)} 2.7 Current to Change State (Note 7) -300 μA 450 (Note 6) 3.6 -450 (Note 7) 3-STATE I/O Leakage $V_O = V_{CC} \text{ or } GND$ 2.3 - 3.6 ±5.0 μA I_{OZ} Power-Off Leakage Current $V_{I} \text{ or } V_{O} = 5.5 V$ 10 I_{OFF} 0 μΑ I_{CC} Quiescent Supply Current $V_I = V_{CC}$ or GND 2.3-3.6 20 μА 500 $V_{IH} = V_{CC} - 0.6V$ 2.3-3.6 μА ΔI_{CC} Increase in I_{CC} per Input Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics

		$\textbf{T}_{\textbf{A}}=-\textbf{40}^{\circ}\textbf{C}$ to $+\textbf{85}^{\circ}\textbf{C},\textbf{R}_{\textbf{L}}=\textbf{500}\Omega$						
Symbol	Parameter	$V_{CC}=3.3V\pm0.3V$ $C_L=50\ pF$		3V V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
	Parameter							
		Min	Max	Min	Max	Min	Max	
t _{PHL}	Propagation Delay	1.0	4.5	1.0	5.2	1.0	5.4	
t _{PLH}	A _n to B _n or B _n to A _n	1.0	4.5	1.0	5.2	1.0	5.4	ns
t _{PZL}	Output Enable Time	1.0	6.5	1.0	7.2	1.0	8.5	
t _{PZH}		1.0	6.5	1.0	7.2	1.0	8.5	ns
t _{PLZ}	Output Disable Time	1.0	6.4	1.0	6.9	1.0	7.7	
t _{PHZ}		1.0	6.4	1.0	6.9	1.0	7.7	ns
t _{OSHL}	Output to Output Skew (Note 8)		1.0					ns
tOSLH			1.0					115

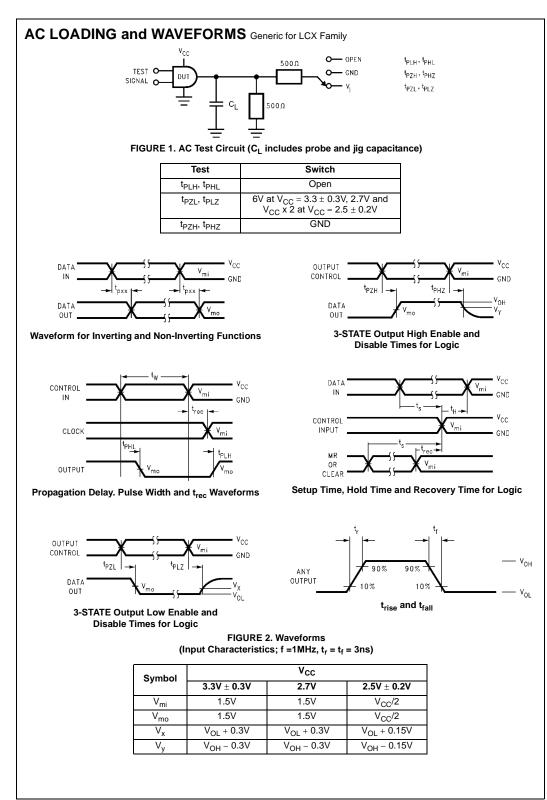
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

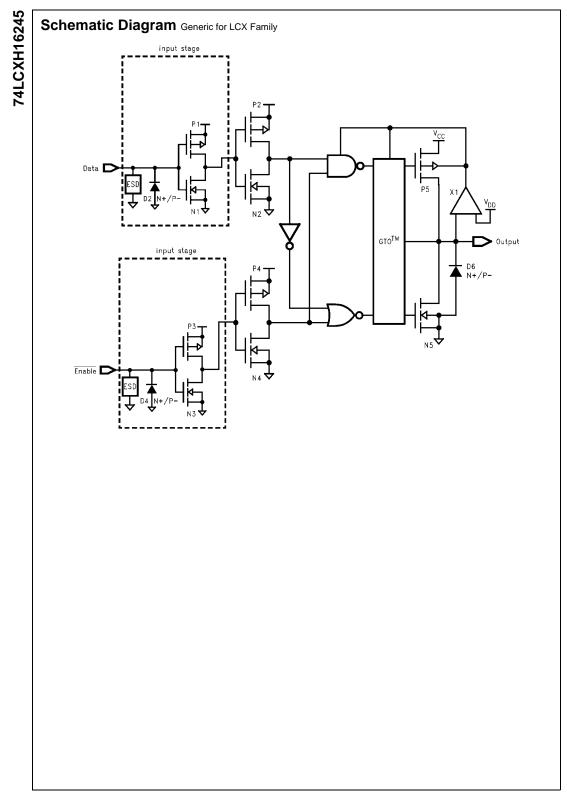
Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_{L} = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

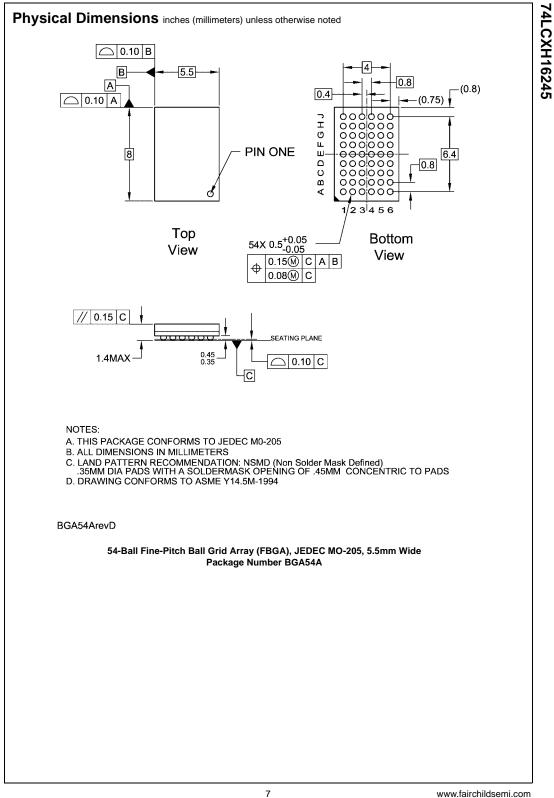
Capacitance

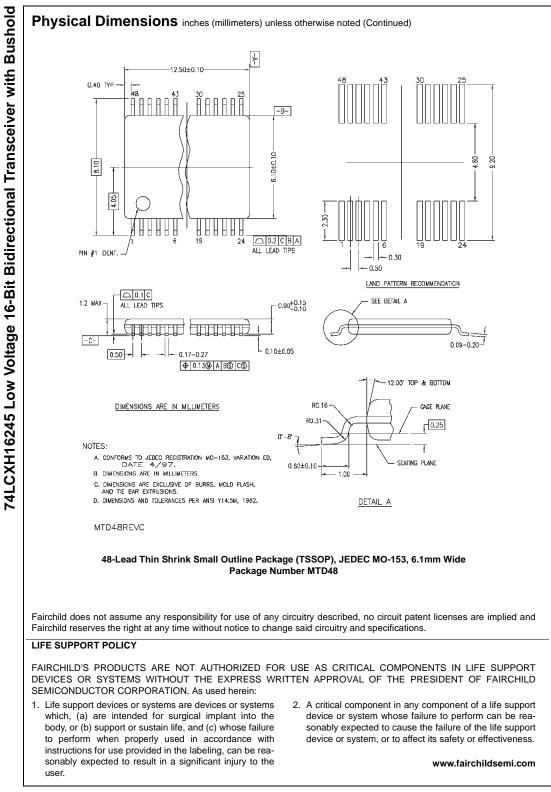
Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF



5







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